

250V N-Ch Power MOSFET
Feature

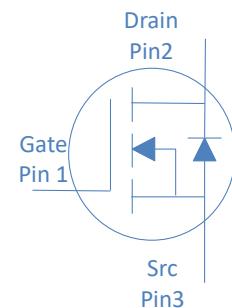
- ◊ High Speed Power Smooth Switching
- ◊ Enhanced Body diode dv/dt capability
- ◊ Enhanced Avalanche Ruggedness
- ◊ 100% UIS Tested, 100% Rg Tested
- ◊ Lead Free

V_{DS}	250	V
$R_{DS(on),typ}$	31	$m\Omega$
I_D (Silicon Limited)	50	A

Application

- ◊ Synchronous Rectification in SMPS
- ◊ Hard Switching and High Speed Circuit
- ◊ Power Tools
- ◊ UPS
- ◊ Motor Control

TO-220

TO-247


Part Number	Package	Marking
HGK390N25S	TO-247	GK390N25S
HGP390N25S	TO-220	GP390N25S

Absolute Maximum Ratings at $T_j=25^\circ C$ (unless otherwise specified)

Parameter	Symbol	Conditions	Value	Unit
Continuous Drain Current (Silicon Limited)	I_D	$T_C=25^\circ C$	50	A
		$T_C=100^\circ C$	36	
Drain to Source Voltage	V_{DS}	-	250	V
Gate to Source Voltage	V_{GS}	-	± 20	V
Pulsed Drain Current	I_{DM}	-	150	A
Avalanche Energy, Single Pulse	E_{AS}	$L=0.4mH, T_C=25^\circ C$	58	mJ
Power Dissipation	P_D	$T_C=25^\circ C$	300	W
Operating and Storage Temperature	T_J, T_{stg}	-	-55 to 175	°C

Absolute Maximum Ratings

Parameter	Symbol	Max	Unit
Thermal Resistance Junction-Case	R_{eJC}	0.5	°C/W
Thermal Resistance Junction-Ambient	R_{eJA}	60	°C/W

Electrical Characteristics at $T_j=25^\circ\text{C}$ (unless otherwise specified)
Static Characteristics

Parameter	Symbol	Conditions	Value			Unit	
			min	typ	max		
Drain to Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_D=250\mu\text{A}$	250	-	-	V	
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{GS}}=V_{\text{DS}}, I_D=250\mu\text{A}$	2	3	4		
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=250\text{V}, T_j=25^\circ\text{C}$	-	-	1	μA	
		$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=250\text{V}, T_j=100^\circ\text{C}$	-	-	100		
Gate to Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA	
Drain to Source on Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_D=20\text{A}$	TO-247	-	31	39	$\text{m}\Omega$
			TO-220		31	39	
Transconductance	g_{fs}	$V_{\text{DS}}=5\text{V}, I_D=20\text{A}$	-	58	-	S	
Gate Resistance	R_G	$V_{\text{GS}}=0\text{V}, V_{\text{DS}} \text{ Open}, f=1\text{MHz}$	-	3.9	-	Ω	

Dynamic Characteristics

Input Capacitance	C_{iss}	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=100\text{V}, f=1\text{MHz}$	-	2905	-	pF
Output Capacitance	C_{oss}		-	172	-	
Reverse Transfer Capacitance	C_{rss}		-	10.7	-	
Total Gate Charge	Q_g	$V_{\text{DD}}=125\text{V}, I_D=20\text{A}, V_{\text{GS}}=10\text{V}$	-	34	-	nC
Gate to Source Charge	Q_{gs}		-	11	-	
Gate to Drain (Miller) Charge	Q_{gd}		-	4.0	-	
Turn on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=125\text{V}, I_D=20\text{A}, V_{\text{GS}}=10\text{V}, R_G=10\Omega,$	-	10	-	ns
Rise time	t_r		-	18	-	
Turn off Delay Time	$t_{\text{d}(\text{off})}$		-	22	-	
Fall Time	t_f		-	8	-	

Reverse Diode Characteristics

Diode Forward Voltage	V_{SD}	$V_{\text{GS}}=0\text{V}, I_F=20\text{A}$	-	0.9	-	V
Reverse Recovery Time	t_{rr}	$V_R=125\text{V}, I_F=20\text{A}, dI_F/dt=100\text{A}/\mu\text{s}$	-	140	-	ns
Reverse Recovery Charge	Q_{rr}		-	630	-	nC



Fig 1. Typical Output Characteristics

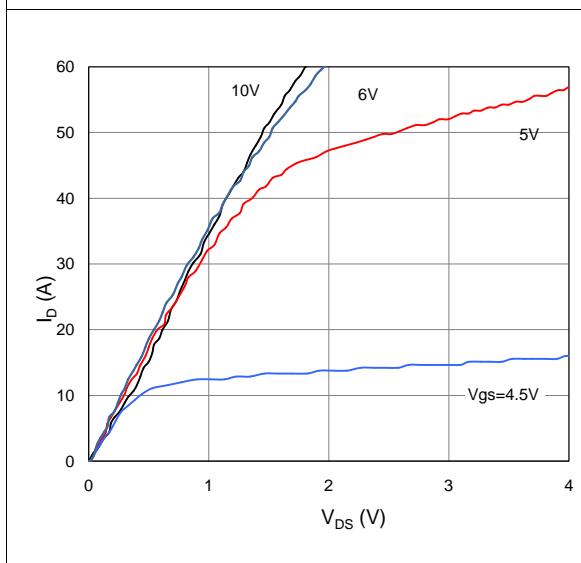


Figure 2. On-Resistance vs. Gate-Source Voltage

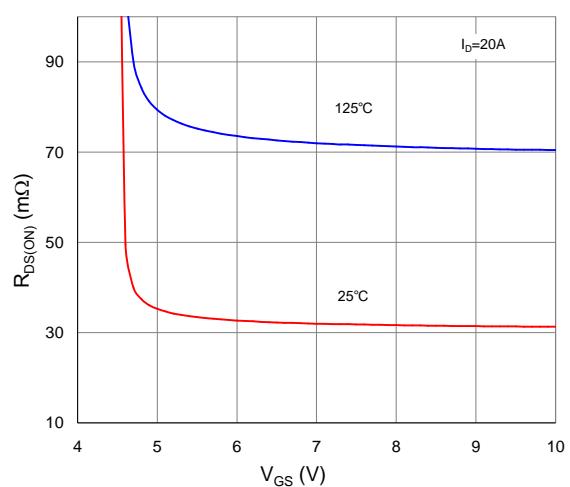


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

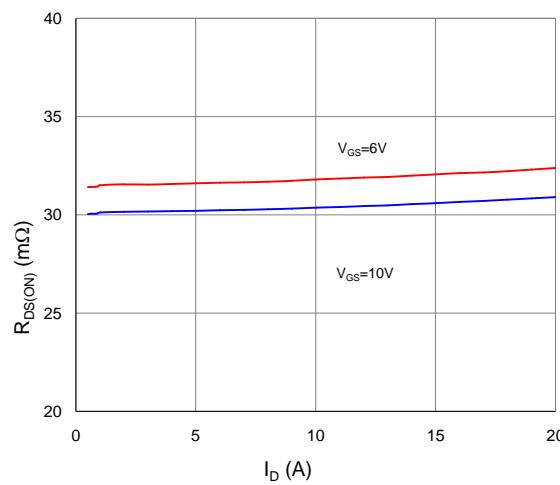


Figure 4. Normalized On-Resistance vs. Junction Temperature

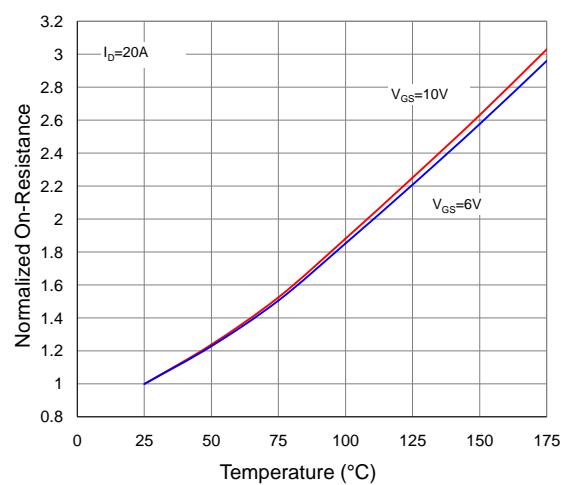


Figure 5. Typical Transfer Characteristics

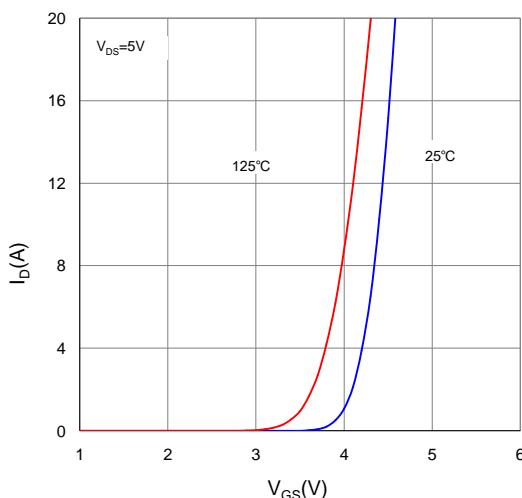


Figure 6. Typical Source-Drain Diode Forward Voltage

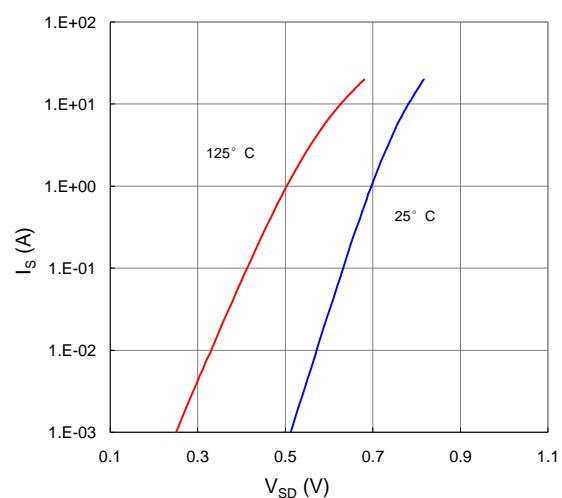




Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage

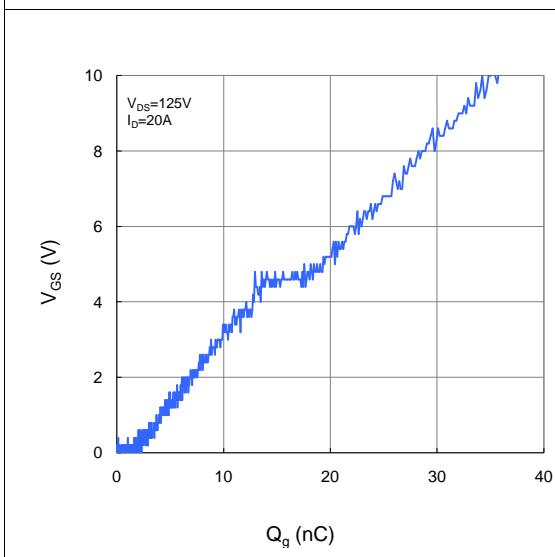


Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

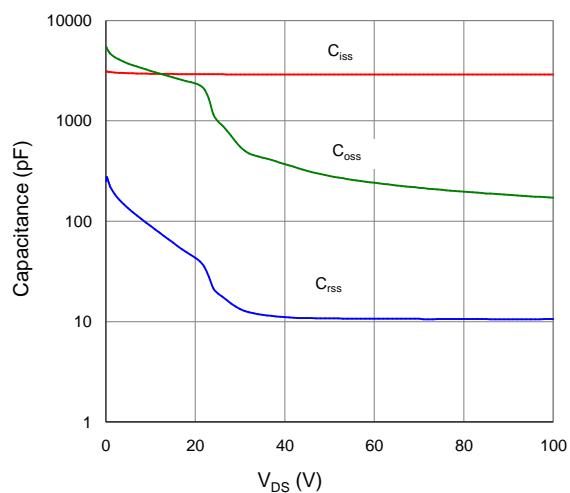


Figure 9. Maximum Safe Operating Area

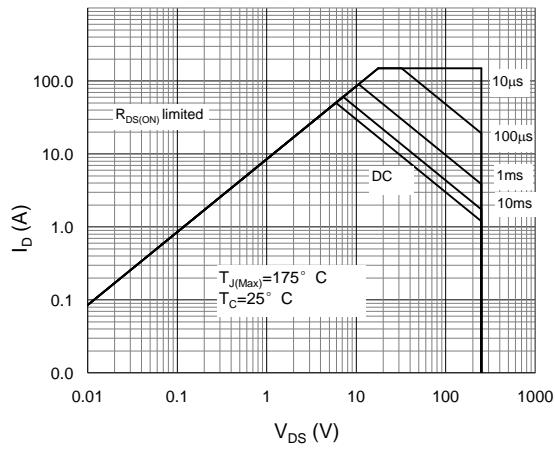


Figure 10. Maximum Drain Current vs. Case Temperature

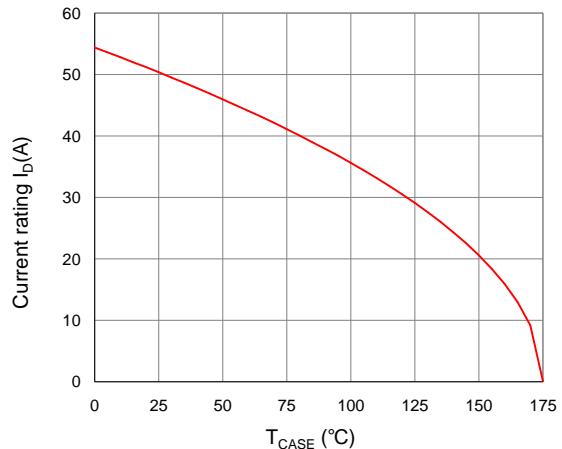
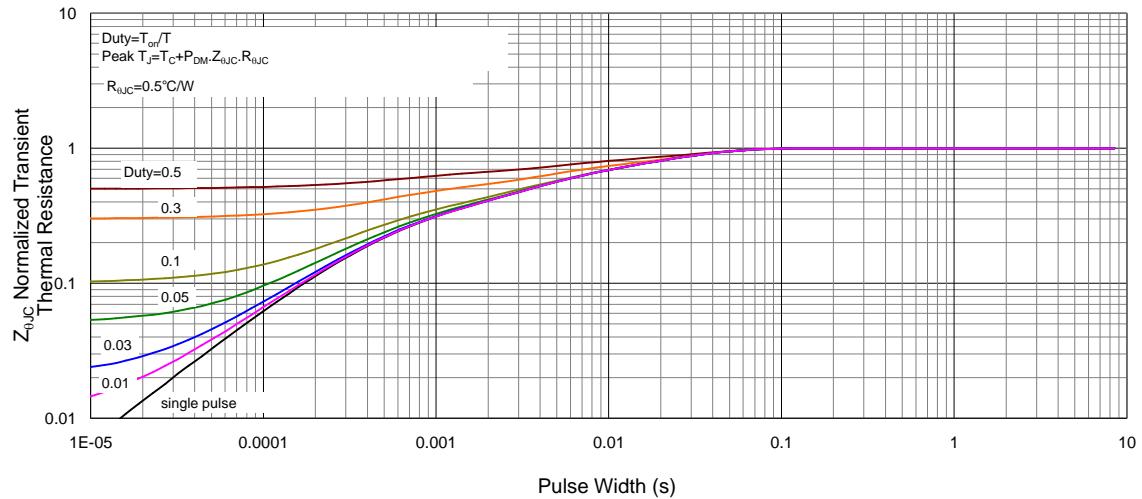


Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Case

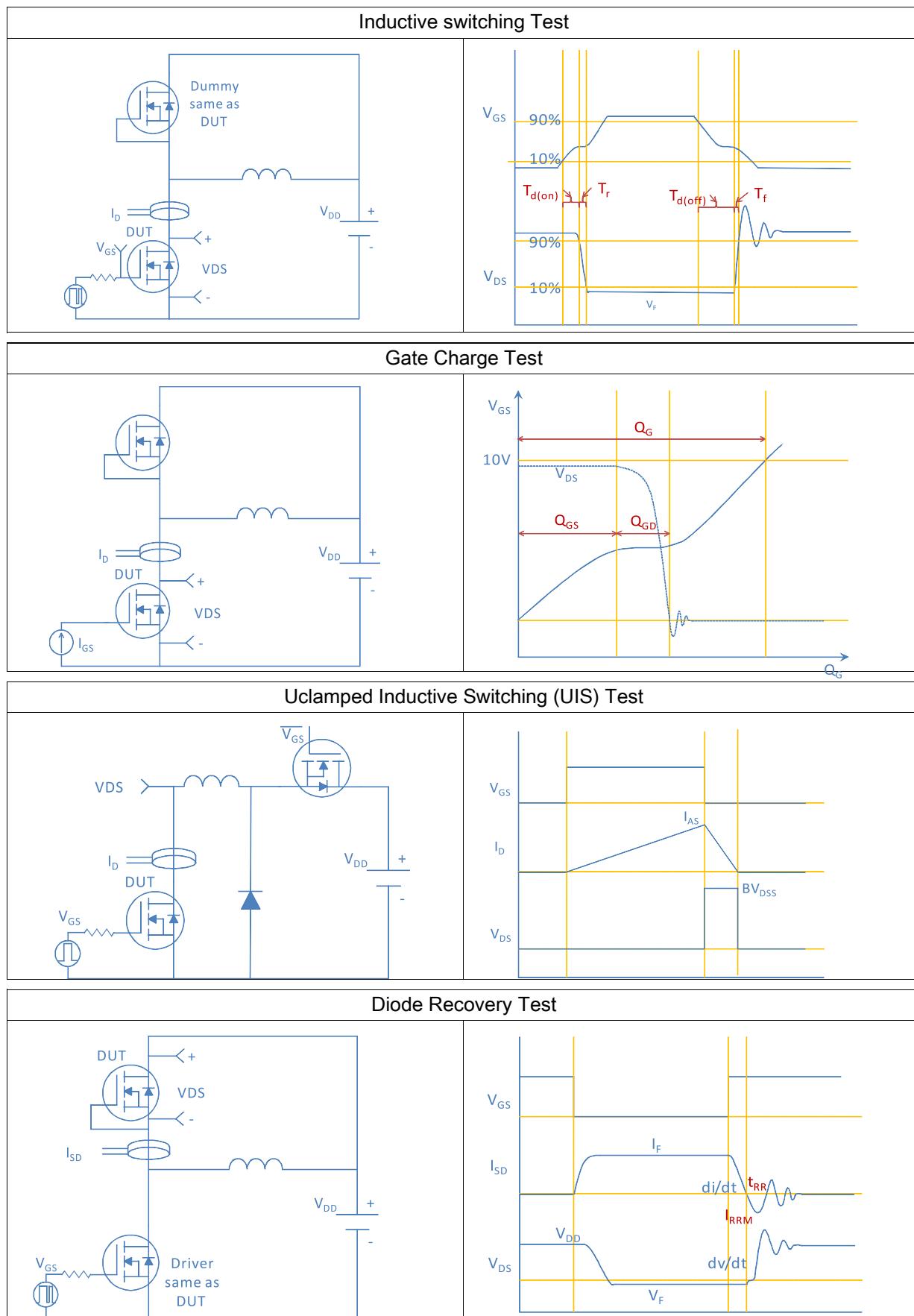


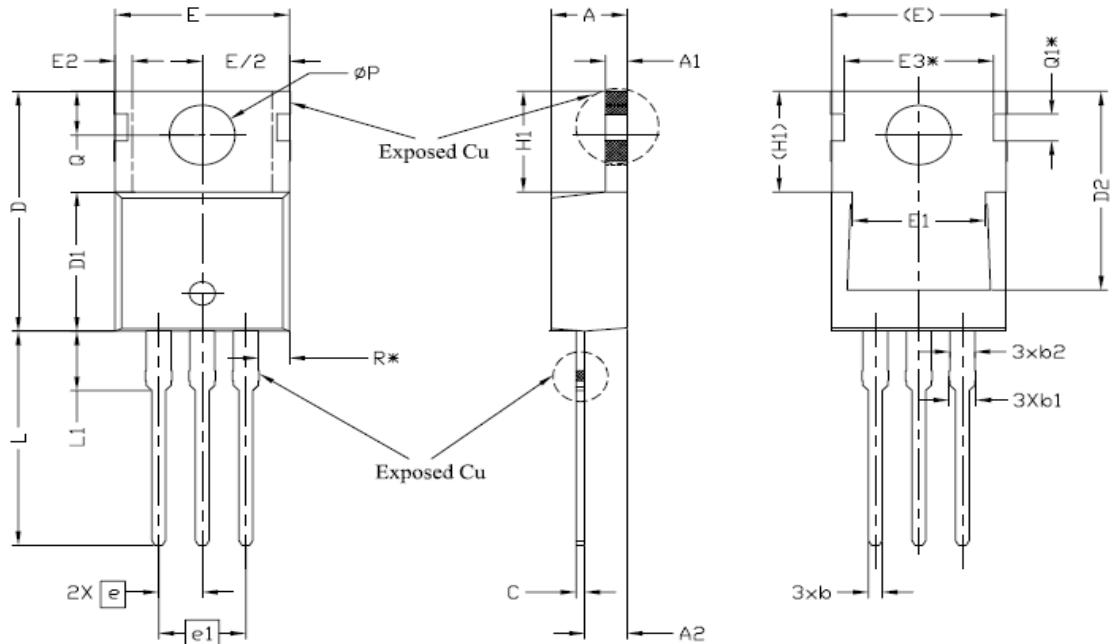


Hunteck

HGK390N25S , HGP390N25S

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TO-220, 3 leads


SYMBOL	DIMENSIONS			NOTES
	MIN.	NOM.	MAX.	
A	4.24	4.44	4.64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
b	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
c	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.63	12.73	12.83	5
E	9.96	10.16	10.36	4,5
E1	6.86	7.77	8.89	5
E2	-	-	0.76	6
E3*	8.70REF.			
e	2.54BSC			
e1	5.08BSC			
H1	6,30	6,45	6,60	5,6
L	13,47	13,72	13,97	
L1	3,60	3,80	4,00	
ØP	3,75	3,84	3,93	
Q	2,60	2,80	3,00	
Q1*	1.73REF.			
R*	1.82REF.			

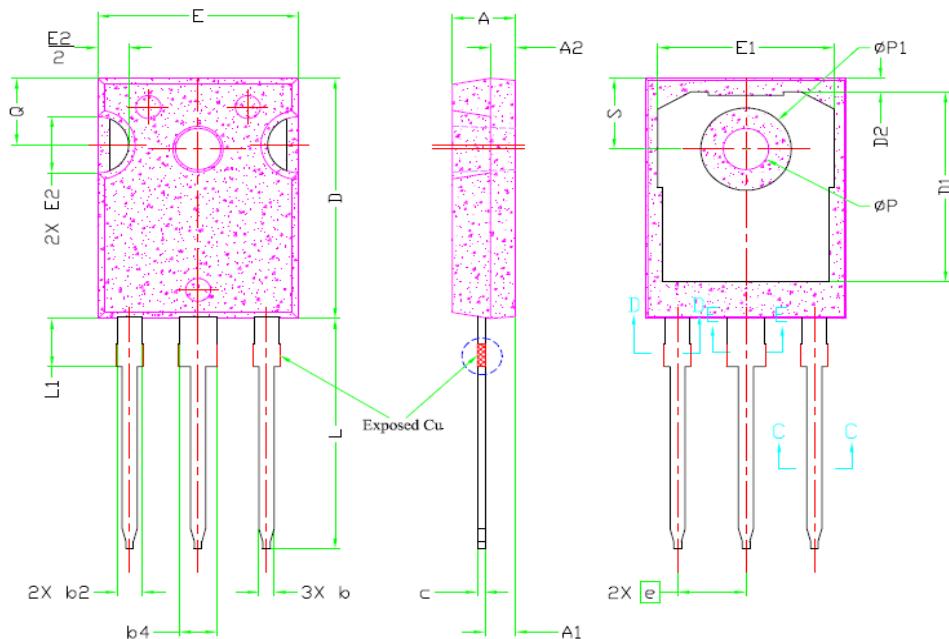


Hunteck

HGK390N25S , HGP390N25S

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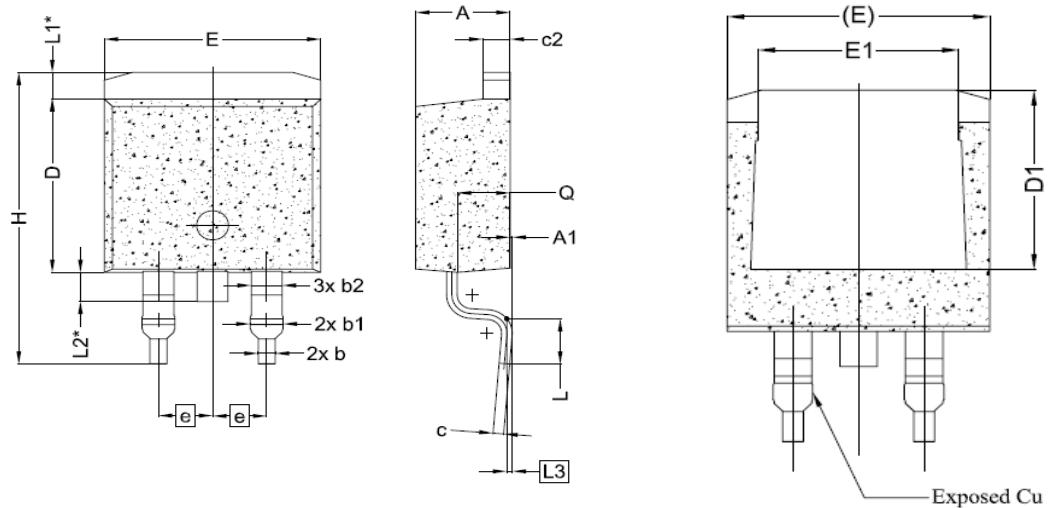
TO-247, 3 leads



SYMBOL	DIMENSIONS			NOTES
	MIN.	NOM.	MAX.	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
b4	2.87	3.00	3.22	6, 8
b5	2.87	3.00	3.18	
c	0.55	0.60	0.69	6
c1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ØP	3.56	3.61	3.65	7
ØP1	7.19REF.			
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	



TO-263, 2 leads



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	4.24	4.44	4.64
A1	0.00	0.10	0.25
b	0.70	0.80	0.90
b1	1.20	1.55	1.75
b2	1.20	1.45	1.70
c	0.40	0.50	0.60
c2	1.15	1.27	1.40
D	8,82	8,92	9,02
D1	6,86	7,65	—
E	9,96	10,16	10,36
E1	6,89	7,77	7,89
e	2.54 BSC		
H	14,61	15,00	15,88
L	1,78	2,32	2,79
L1	1.36 REF.		
L2	1.50 REF.		
L3	0.25 BSC		
Q	2.30	2.48	2.70